

## ATF-35143 Low Noise Pseudomorphic HEMT in a Surface Mount Plastic Package

Data Sheet

### Description

Agilent's ATF-35143 is a high dynamic range, low noise, PHEMT housed in a 4-lead SC-70 (SOT-343) surface mount plastic package.

Based on its featured performance, ATF-35143 is suitable for applications in cellular and PCS base stations, LEO systems, MMDS, and other systems requiring super low noise figure with good intercept in the 450 MHz to 10 GHz frequency range.

Other PHEMT devices in this family are the ATF-34143 and the ATF-33143. The typical specifications for these devices at 2 GHz are shown in the table below: Surface Mount Package SOT-343



### Pin Connections and Package Marking



**Note:** Top View. Package marking provides orientation and identification.

"5P" = Device code

"x" = Date code character. A new character is assigned for each month, year.

Part No.	Gate Width	<b>Bias Point</b>	NF (dB)	Ga (dB)	OIP3 (dBm)
ATF-33143	$1600\mu$	4 V, 80 mA	0.5	15.0	33.5
ATF-34143	800 µ	4V, 60 mA	0.5	17.5	31.5
ATF-35143	400 μ	2 V, 15 mA	0.4	18.0	21.0



Attention: Observe precautions for handling electrostatic sensitive devices.

ESD Machine Model (Class A)

ESD Human Body Model (Class 1)

Refer to Agilent Application Note A004R: Electrostatic Discharge Damage and Control.

# Lead-free Option AvailableLow Noise Figure

Features

- Excellent Uniformity in Product Specifications
- Low Cost Surface Mount Small Plastic Package SOT-343 (4 lead SC-70)
- Tape-and-Reel Packaging Option Available

### **Specifications**

1.9 GHz; 2V, 15 mA (Typ.)

- 0.4 dB Noise Figure
- 18 dB Associated Gain
- 11 dBm Output Power at 1 dB Gain Compression
- 21 dBm Output 3<sup>rd</sup> Order Intercept

### Applications

- Low Noise Amplifier for Cellular/PCS Handsets
- LNA for WLAN, WLL/RLL, LEO, and MMDS Applications
- General Purpose Discrete PHEMT for Other Ultra Low Noise Applications



		0	
Symbol	Parameter	Units	Absolute Maximum
V <sub>DS</sub>	Drain - Source Voltage <sup>[2]</sup>	V	5.5
V <sub>GS</sub>	Gate - Source Voltage <sup>[2]</sup>	V	-5
V <sub>GD</sub>	Gate Drain Voltage <sup>[2]</sup>	V	-5
I <sub>DS</sub>	Drain Current <sup>[2]</sup>	mA	I <sub>dss</sub> <sup>[3]</sup>
P <sub>diss</sub>	Total Power Dissipation <sup>[4]</sup>	mW	300
P <sub>in max</sub>	RF Input Power	dBm	14
T <sub>CH</sub>	Channel Temperature	°C	160
T <sub>STG</sub>	Storage Temperature	°C	-65 to 160
$\theta_{jc}$	Thermal Resistance <sup>[5]</sup>	°C/W	310

### ATF-35143 Absolute Maximum Ratings<sup>[1]</sup>

#### Notes:

- Operation of this device above any one of these parameters may cause permanent damage.
- 2. Assumes DC quiesent conditions. 3.  $V_{GS} = 0 V$
- 4. Source lead temperature is 25°C. Derate 3.2 mW/°C for  $T_L > 67$ °C.
- Thermal resistance measured using 150°C Liquid Crystal Measurement method.



Figure 1. Typical Pulsed I-V Curves<sup>[6]</sup>.  $(V_{GS} = -0.2 V \text{ per step})$ 



LSL=0.2, Nominal=0.37, USL=0.7

#### Notes:

### **Product Consistency Distribution Charts**<sup>[7, 8]</sup>



Figure 2. OIP3 @ 2 GHz, 2 V, 15 mA. LSL=19.0, Nominal=20.9, USL=23.0





- Distribution data sample size is 450 samples taken from 9 different wafers. Future wafers allocated to this product may have nominal values anywhere within the upper and lower spec limits.
- Measurements made on production test board. This circuit represents a trade-off between an optimal noise match and a realizeable match based on production test requirements. Circuit losses have been deembedded from actual measurements.

### **ATF-35143 Electrical Specifications**

 $T_{\rm A}$  = 25°C, RF parameters measured in a test circuit for a typical device

Symbol	Parameter	s and Test C	onditions	Units	Min.	<b>Typ.</b> <sup>[2]</sup>	Max.
I <sub>dss</sub> <sup>[1]</sup>	Saturated Drain Curren	nt	$V_{\rm DS}=1.5~V,~V_{\rm GS}=0~V$	mA	40	65	80
$V_{P}^{[1]}$	Pinchoff Voltage	V <sub>DS</sub>	= 1.5 V, $I_{DS}$ = 10% of $I_{dss}$	V	-0.65	-0.5	-0.35
Id	Quiescent Bias Curren	t	$V_{GS}$ = 0.45 V, $V_{DS}$ = 2 V	mA		15	
g <sub>m</sub> <sup>[1]</sup>	Transconductance		$V_{\rm DS}$ = 1.5 V, $g_m$ = $I_{dss}/V_P$	mmho	90	120	
I <sub>GDO</sub>	Gate to Drain Leakage	Current	$V_{GD} = 5 V$	μΑ			250
Igss	Gate Leakage Current		$V_{GD} = V_{GS} = -4 \ V$	μA		10	150
		f = 2 GHz	$V_{\rm DS}$ = 2 V, $I_{\rm DS}$ = 15 mA	dB		0.4	0.7
NF	Noise Figure <sup>[3]</sup>		$V_{\rm DS} = 2 \text{ V}, \text{ I}_{\rm DS} = 5 \text{ mA}$			0.5	0.9
	ga a	f = 900 MHz	$V_{\rm DS} = 2 \text{ V}, I_{\rm DS} = 15 \text{ mA}$	dB		0.3	
			$V_{\rm DS} = 2 \text{ V}, I_{\rm DS} = 5 \text{ mA}$			0.4	
		f = 2 GHz	$V_{\rm DS} = 2$ V, $I_{\rm DS} = 15$ mA	dB	16.5	18	19.5
Ga	Associated Gain <sup>[3]</sup>		$V_{\rm DS} = 2 \text{ V}, \text{ I}_{\rm DS} = 5 \text{ mA}$		14	16	18
a		f = 900 MHz	$V_{\rm DS} = 2$ V, $I_{\rm DS} = 15$ mA	dB		20	
			$V_{\rm DS}$ = 2 V, $I_{\rm DS}$ = 5 mA			18	
		f = 2 GHz	$V_{\rm DS}$ = 2 V, $I_{\rm DS}$ = 15 mA	dBm	19	21	
OIP3	Output 3 <sup>rd</sup> Order		$V_{DS} = 2 V$ , $I_{DS} = 5 mA$			14	
	Intercept Point <sup>[4, 5]</sup>	f = 900  MHz	$V_{\rm DS} = 2$ V, $I_{\rm DS} = 15$ mA	dBm		19	
			$V_{DS} = 2 V$ , $I_{DS} = 5 mA$			14	
		f = 2 GHz	$V_{\rm DS} = 2$ V, $I_{\rm DSQ} = 15$ mA	dBm		10	
P <sub>1</sub> m	1 dB Compressed		$V_{\rm DS} = 2$ V, $I_{\rm DSQ} = 5$ mA			8	
I 1dB	Intercept Point <sup>[4]</sup>	f = 900 MHz	$V_{\rm DS}$ = 2 V, $I_{\rm DSQ}$ = 15 mA	dBm		9	
			$V_{\rm DS}$ = 2 V, $I_{\rm DSQ}$ = 5 mA			9	

Notes:

1. Guaranteed at wafer probe level

2. Typical value determined from a sample size of 450 parts from 9 wafers.

3. 2V5 mA min/max data guaranteed via the 2V15 mA production test.

4. Measurements obtained using production test board described in Figure 5.

5.  $P_{out} = -10 \text{ dBm per tone}$ 



Figure 5. Block diagram of 2 GHz production test board used for Noise Figure, Associated Gain,  $P_{1dB}$ , and OIP3 measurements. This circuit represents a trade-off between an optimal noise match and a realizable match based on production test requirements. Circuit losses have been de-embedded from actual measurements.

### **ATF-35143 Typical Performance Curves**







Figure 8. NF and G<sub>a</sub> vs. Bias at 2 GHz.<sup>[1]</sup>







Figure 7. OIP3 and  $P_{1dB}$  vs. Bias at 900 MHz. $^{\left[1,2\right]}$ 







Figure 11. P<sub>1dB</sub> vs. Bias (Active Bias) Tuned for NF @ 2V, 15 mA at 900 MHz.<sup>[1]</sup>

#### Notes:

- 1. Measurements made on a fixed tuned production test board that was tuned for optimal gain match with reasonable noise figure at 2V 15 mA bias. This circuit represents a trade-off between optimal noise match, maximum gain match and a realizable match based on production test board requirements. Circuit losses have been de-embedded from actual measurements.
- 2.  $P_{1dB}$  measurements are performed with passive biasing. Quiescent drain current,  $I_{DSQ}$ , is set with zero RF drive applied. As  $P_{1dB}$  is approached, the drain current may increase or decrease depending on frequency and dc bias point. At lower values of  $I_{DSQ}$  the device is running closer to class B as power output approaches  $P_{1dB}$ . This results in higher  $P_{1dB}$  and higher PAE (power added efficiency) when compared to a device that is driven by a constant current source as is typically done with active biasing. As an example, at a  $V_{DS}$  = 4 V and  $I_{DSQ}$  = 5 mA,  $I_d$  increases to 30 mA as a  $P_{1dB}$  of +15 dBm is approached.









Figure 14.  $F_{min}$  and  $G_a$  vs. Frequency and Temperature,  $V_{DS}$ =2V,  $I_{DS}$ =15 mA.



Figure 16. OIP3, P<sub>1dB</sub>, NF and Gain vs. Bias<sup>[1]</sup> (Active Bias, 2V, 3.9 GHz).



Figure 13. Associated Gain vs. Frequency and Current at 2V.



Figure 15. OIP3 and  $P_{1dB}$  vs. Frequency and Temperature<sup>[1,2]</sup>,  $V_{DS}$ =2V,  $I_{DS}$ =15 mA.



Figure 17. OIP3, P<sub>1dB</sub>, NF and Gain vs. Bias<sup>[1]</sup> (Active Bias, 2V, 5.8 GHz).

Notes:

- 1. Measurements made on a fixed tuned test fixture that was tuned for noise figure at 2V 15mA bias. This circuit represents a trade-off between optimal noise match, maximum gain match and a realizable match based on production test requirements. Circuit losses have been de-embedded from actual measurements.
- 2.  $P_{1dB}$  measurements are performed with passive biasing. Quiescent drain current,  $I_{DSQ}$ , is set with zero RF drive applied. As  $P_{1dB}$  is approached, the drain current may increase or decrease depending on frequency and dc bias point. At lower values of  $I_{dsq}$  the device is running closer to class B as power output approaches  $P_{1dB}$ . This results in higher  $P_{1dB}$  and higher PAE (power added efficiency) when compared to a device that is driven by a constant current source as is typically done with active biasing. As an example, at a  $V_{DS} = 4V$  and  $I_{DSQ} = 5$  mA,  $I_d$  increases to 30 mA as a  $P_{1dB}$  of +15 dBm is approached.

Freq.	S <sub>11</sub>			$\mathbf{S}_{21}$			$\mathbf{S}_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-16.90	13.34	4.64	166.04	-31.70	0.026	77.91	0.73	-12.47	22.52
0.75	0.98	-26.37	13.29	4.62	157.78	-28.18	0.039	71.12	0.72	-17.53	20.83
1.00	0.97	-34.76	13.16	4.55	150.72	-25.85	0.051	65.76	0.71	-23.33	19.50
1.50	0.94	-50.59	12.83	4.38	137.02	-22.73	0.073	54.85	0.68	-34.88	17.78
1.75	0.91	-58.26	12.66	4.30	130.38	-21.62	0.083	49.69	0.67	-40.49	17.13
2.00	0.90	-65.74	12.44	4.19	123.90	-20.72	0.092	44.45	0.65	-46.03	16.58
2.50	0.85	-80.62	12.04	4.00	111.27	-19.33	0.108	34.61	0.62	-56.68	15.69
3.00	0.81	-95.48	11.61	3.81	99.08	-18.27	0.122	25.21	0.59	-66.71	14.94
4.00	0.72	-125.99	10.71	3.43	75.75	-17.08	0.140	6.95	0.52	-85.11	13.89
5.00	0.66	-156.09	9.79	3.09	53.63	-16.48	0.150	-9.83	0.45	-102.71	13.13
6.00	0.62	174.97	8.93	2.80	32.77	-16.14	0.156	-25.73	0.38	-120.16	12.53
7.00	0.60	145.61	8.06	2.53	12.43	-16.08	0.157	-41.00	0.31	-138.01	12.07
8.00	0.60	118.39	7.20	2.29	-7.12	-16.31	0.153	-54.14	0.25	-157.10	11.75
9.00	0.62	93.15	6.26	2.06	-26.14	-16.59	0.148	-67.05	0.20	-178.27	11.19
10.00	0.66	71.31	5.43	1.87	-44.14	-16.89	0.143	-78.09	0.16	157.62	9.63
11.00	0.70	50.91	4.58	1.69	-62.85	-17.14	0.139	-88.99	0.14	121.82	8.81
12.00	0.72	31.04	3.64	1.52	-81.42	-17.52	0.133	-100.38	0.17	82.33	7.87
13.00	0.74	11.26	2.56	1.34	-99.46	-18.13	0.124	-111.06	0.22	53.17	6.79
14.00	0.76	-3.08	1.45	1.18	-115.94	-18.79	0.115	-119.00	0.28	27.32	5.86
15.00	0.82	-14.26	0.43	1.05	-132.24	-19.25	0.109	-127.12	0.34	6.01	5.89
16.00	0.82	-26.64	-0.72	0.92	-149.24	-19.58	0.105	-135.42	0.42	-10.69	4.84
17.00	0.84	-38.94	-1.83	0.81	-164.44	-19.74	0.103	-143.49	0.49	-22.32	4.62
18.00	0.86	-54.78	-3.02	0.71	179.28	-20.18	0.098	-152.36	0.56	-35.90	4.04

ATF-35143 Typical Scattering Parameters,  $V_{DS} = 2 V$ ,  $I_{DS} = 5 mA$ 

 $V_{DS} = 2 V, I_{DS} = 5 mA$ 

Freq.	<b>F</b> <sub>min</sub>	Γ	pt	R <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.10	0.91	6.4	0.22	19.3
0.9	0.12	0.87	15.0	0.22	17.9
1.0	0.14	0.86	17.2	0.22	17.5
1.5	0.20	0.81	28.0	0.22	16.3
1.8	0.23	0.78	33.4	0.21	15.8
2.0	0.27	0.76	38.8	0.21	15.4
2.5	0.33	0.71	50.0	0.19	14.7
3.0	0.39	0.66	61.9	0.17	14.0
4.0	0.52	0.58	87.2	0.13	12.7
5.0	0.64	0.52	114.4	0.09	11.5
6.0	0.77	0.47	143.2	0.06	10.4
7.0	0.89	0.43	173.5	0.05	9.5
8.0	1.02	0.41	-155.2	0.07	8.7
9.0	1.14	0.40	-122.9	0.13	8.0
10.0	1.27	0.41	-90.1	0.24	7.5



#### Notes:

 $1. \ F_{min} \ values \ at 2 \ GHz \ and \ higher \ are \ based \ on \ measurements \ while \ the \ F_{mins} \ below \ 2 \ GHz \ have \ been \ extrapolated. \ The \ F_{min} \ values \ are \ based \ on \ a \ set \ of \ 16 \ noise \ figure \ measurements \ made \ at \ 16 \ different \ impedances \ using \ an \ ATN \ NP5 \ test \ system. \ From \ these \ measurements \ a \ true \ F_{min} \ is \ calculated. \ Refer \ to \ the \ noise \ parameter \ application \ setting \ and \$ 

Freq.	$\mathbf{S}_{11}$			$S_{21}$			$S_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-18.75	15.89	6.23	164.76	-32.40	0.024	77.63	0.63	-14.09	24.14
0.75	0.97	-29.11	15.79	6.16	155.98	-28.87	0.036	70.58	0.61	-19.69	22.30
1.00	0.95	-38.28	15.61	6.03	148.42	-26.56	0.047	64.88	0.60	-26.10	21.08
1.50	0.91	-55.52	15.17	5.73	133.92	-23.61	0.066	54.16	0.57	-38.73	19.39
1.75	0.89	-63.78	14.92	5.57	127.01	-22.62	0.074	49.11	0.56	-44.79	18.75
2.00	0.86	-71.82	14.65	5.40	120.27	-21.72	0.082	44.08	0.54	-50.70	18.19
2.50	0.81	-87.59	14.11	5.08	107.36	-20.35	0.096	34.60	0.51	-61.95	17.23
3.00	0.76	-103.22	13.54	4.76	95.04	-19.41	0.107	25.71	0.47	-72.47	16.48
4.00	0.66	-134.81	12.40	4.17	71.95	-18.27	0.122	9.04	0.41	-91.47	15.34
5.00	0.61	-165.34	11.29	3.67	50.43	-17.65	0.131	-5.97	0.34	-110.05	14.47
6.00	0.58	165.88	10.27	3.26	30.28	-17.33	0.136	-20.15	0.27	-129.24	13.80
7.00	0.57	137.00	9.27	2.91	10.68	-17.14	0.139	-33.84	0.21	-150.49	13.21
8.00	0.58	110.78	8.33	2.61	-8.09	-17.14	0.139	-45.60	0.17	-174.77	12.73
9.00	0.61	86.75	7.32	2.32	-26.38	-17.20	0.138	-57.65	0.13	154.01	10.69
10.00	0.65	66.25	6.44	2.10	-43.90	-17.20	0.138	-68.22	0.11	118.18	9.85
11.00	0.69	46.88	5.54	1.89	-61.97	-17.27	0.137	-79.30	0.14	78.36	9.16
12.00	0.72	27.76	4.56	1.69	-79.90	-17.39	0.135	-90.87	0.19	49.57	8.34
13.00	0.74	8.62	3.45	1.49	-97.18	-17.79	0.129	-102.19	0.26	29.95	7.35
14.00	0.77	-5.28	2.33	1.31	-112.92	-18.20	0.123	-110.80	0.33	9.45	6.51
15.00	0.82	-16.03	1.29	1.16	-128.66	-18.56	0.118	-120.09	0.39	-7.98	6.51
16.00	0.82	-28.32	0.19	1.02	-144.87	-18.79	0.115	-129.92	0.45	-22.30	5.48
17.00	0.84	-40.43	-0.87	0.91	-159.49	-18.79	0.115	-139.60	0.51	-32.23	5.24
18.00	0.86	-56.14	-1.99	0.80	-175.19	-19.33	0.108	-149.17	0.57	-44.43	4.72

ATF-35143 Typical Scattering Parameters,  $V_{DS} = 2 \text{ V}$ ,  $I_{DS} = 10 \text{ mA}$ 

 $V_{DS} = 2 V, I_{DS} = 10 mA$ 

Freq.	<b>F</b> <sub>min</sub>	Γ	pt	<b>R</b> <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.10	0.88	5.0	0.15	20.5
0.9	0.11	0.84	14.0	0.15	19.0
1.0	0.12	0.83	16.0	0.15	18.6
1.5	0.17	0.77	26.0	0.15	17.5
1.8	0.20	0.74	31.9	0.15	16.9
2.0	0.23	0.71	37.3	0.14	16.4
2.5	0.29	0.66	48.6	0.14	15.7
3.0	0.34	0.60	60.6	0.12	15.0
4.0	0.46	0.52	86.8	0.12	13.6
5.0	0.58	0.45	115.3	0.08	12.4
6.0	0.69	0.40	145.8	0.05	11.3
7.0	0.81	0.37	177.7	0.05	10.3
8.0	0.92	0.35	-149.3	0.07	9.5
9.0	1.04	0.35	-115.6	0.12	8.8
10.0	1.16	0.37	-81.8	0.22	8.3



#### Notes:

 $1. \ \ F_{min} \ values at 2 \ GHz \ and higher are based on measurements while the \ F_{mins} \ below 2 \ GHz \ have been extrapolated. The \ F_{min} \ values are based on a set of 16 noise figure measurements made at sixteen different impedances using an ATN NP5 test system. From these measurements a true \ F_{min} \ is calculated. Refer to the noise parameter application section for more information.$ 

Freq.	$\mathbf{S}_{11}$			$\mathbf{S}_{21}$			$\mathbf{S}_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-19.75	17.02	7.10	164.04	-32.77	0.023	77.60	0.57	-14.99	24.89
0.75	0.97	-30.58	16.90	7.00	154.98	-29.37	0.034	70.54	0.55	-20.86	23.05
1.00	0.95	-40.15	16.69	6.83	147.18	-27.13	0.044	64.80	0.54	-27.61	21.91
1.50	0.90	-58.08	16.18	6.44	132.28	-24.15	0.062	54.23	0.51	-40.74	20.17
1.75	0.87	-66.65	15.90	6.23	125.22	-23.10	0.070	49.25	0.49	-46.95	19.53
2.00	0.84	-74.93	15.59	6.02	118.41	-22.27	0.077	44.36	0.48	-53.06	18.93
2.50	0.79	-91.13	14.97	5.61	105.38	-20.92	0.090	35.36	0.44	-64.59	17.95
3.00	0.73	-107.08	14.34	5.21	93.08	-20.00	0.100	26.85	0.41	-75.32	17.17
4.00	0.64	-139.07	13.09	4.51	70.17	-18.94	0.113	11.15	0.35	-94.59	16.01
5.00	0.59	-169.70	11.90	3.93	49.03	-18.27	0.122	-2.96	0.29	-113.89	15.09
6.00	0.56	161.74	10.81	3.47	29.27	-17.79	0.129	-16.43	0.23	-134.46	14.30
7.00	0.56	133.19	9.77	3.08	10.04	-17.59	0.132	-29.47	0.17	-158.65	13.68
8.00	0.57	107.56	8.78	2.75	-8.35	-17.46	0.134	-40.80	0.14	172.14	12.29
9.00	0.60	84.16	7.75	2.44	-26.29	-17.39	0.135	-52.63	0.11	134.01	10.74
10.00	0.64	64.19	6.86	2.20	-43.56	-17.33	0.136	-63.33	0.12	95.85	9.99
11.00	0.68	45.46	5.93	1.98	-61.33	-17.27	0.137	-74.77	0.16	63.20	9.34
12.00	0.72	26.66	4.93	1.76	-78.94	-17.27	0.137	-86.46	0.22	40.01	8.57
13.00	0.74	7.70	3.80	1.55	-95.93	-17.59	0.132	-98.11	0.29	23.11	7.62
14.00	0.77	-5.93	2.68	1.36	-111.53	-17.92	0.127	-107.51	0.36	3.55	6.79
15.00	0.82	-16.54	1.63	1.21	-126.76	-18.20	0.123	-117.16	0.41	-12.09	6.76
16.00	0.82	-28.76	0.54	1.06	-142.70	-18.49	0.119	-127.03	0.47	-26.21	5.81
17.00	0.84	-40.79	-0.49	0.95	-157.02	-18.49	0.119	-137.06	0.53	-35.57	5.55
18.00	0.86	-56.40	-1.60	0.83	-172.47	-18.94	0.113	-147.50	0.58	-47.29	5.06

ATF-35143 Typical Scattering Parameters,  $V_{\rm DS}$  = 2 V,  $I_{\rm DS}$  = 15 mA

 $V_{DS} = 2 V, I_{DS} = 15 mA$ 

Freq.	<b>F</b> <sub>min</sub>	Γ	pt	R <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.10	0.88	4.5	0.19	20.9
0.9	0.13	0.83	13.1	0.17	19.4
1.0	0.14	0.82	15.3	0.16	19.2
1.5	0.19	0.76	26.1	0.15	17.9
1.8	0.22	0.72	32.6	0.15	17.3
2.0	0.23	0.70	36.9	0.14	17.0
2.5	0.29	0.64	48.5	0.12	16.2
3.0	0.34	0.58	60.9	0.07	15.4
4.0	0.45	0.49	87.9	0.13	14.1
5.0	0.56	0.42	117.4	0.07	12.8
6.0	0.67	0.37	149.0	0.05	11.7
7.0	0.79	0.34	-178.1	0.05	10.8
8.0	0.90	0.33	-144.3	0.07	9.9
9.0	1.01	0.34	-110.2	0.13	9.2
10.0	1.12	0.36	-76.3	0.23	8.6



#### Notes:

 $1. \ \ F_{min} \ values at 2 \ GHz \ and higher are based on measurements while the \ F_{mins} \ below 2 \ GHz \ have been extrapolated. The \ F_{min} \ values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATF NP5 test system. From these measurements a true \ F_{min} \ is calculated. Refer to the noise parameter application section for more information.$ 

Freq.	<b>S</b> <sub>11</sub>			$\mathbf{S}_{21}$			$S_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-20.95	18.17	8.10	163.18	-33.56	0.021	77.39	0.49	-15.99	25.87
0.75	0.96	-32.34	18.02	7.96	153.79	-30.17	0.031	70.55	0.47	-22.00	24.10
1.00	0.94	-42.36	17.77	7.73	145.67	-27.96	0.040	65.08	0.46	-29.03	22.86
1.50	0.88	-61.09	17.18	7.22	130.36	-25.04	0.056	54.79	0.43	-42.64	21.11
1.75	0.85	-69.98	16.85	6.96	123.20	-24.01	0.063	50.12	0.41	-48.96	20.42
2.00	0.82	-78.53	16.50	6.69	116.28	-23.22	0.069	45.58	0.39	-55.19	19.86
2.50	0.76	-95.14	15.81	6.17	103.17	-21.94	0.080	37.15	0.36	-66.91	18.87
3.00	0.70	-111.48	15.11	5.69	90.88	-21.01	0.089	29.29	0.34	-77.74	18.06
4.00	0.61	-143.89	13.73	4.86	68.24	-19.83	0.102	14.76	0.28	-97.29	16.78
5.00	0.56	-174.55	12.46	4.20	47.48	-19.02	0.112	1.63	0.23	-117.24	15.74
6.00	0.55	157.19	11.31	3.68	28.10	-18.49	0.119	-10.98	0.17	-139.78	14.90
7.00	0.55	129.18	10.22	3.24	9.28	-18.13	0.124	-23.67	0.13	-169.09	14.17
8.00	0.56	104.19	9.20	2.88	-8.75	-17.79	0.129	-34.72	0.11	155.22	11.98
9.00	0.60	81.48	8.15	2.56	-26.37	-17.59	0.132	-46.33	0.11	112.23	10.82
10.00	0.64	62.07	7.24	2.30	-43.37	-17.33	0.136	-57.43	0.13	77.30	10.15
11.00	0.68	43.83	6.29	2.06	-60.90	-17.20	0.138	-68.78	0.18	51.74	9.51
12.00	0.72	25.46	5.27	1.84	-78.22	-17.14	0.139	-81.32	0.24	32.67	8.77
13.00	0.74	6.81	4.14	1.61	-94.88	-17.33	0.136	-93.11	0.31	17.81	7.87
14.00	0.77	-6.74	3.01	1.41	-110.07	-17.65	0.131	-103.06	0.38	0.45	7.08
15.00	0.82	-17.21	1.94	1.25	-125.15	-17.86	0.128	-112.88	0.43	-15.44	7.06
16.00	0.83	-29.31	0.87	1.11	-140.80	-18.06	0.125	-123.55	0.49	-29.37	6.13
17.00	0.85	-41.30	-0.15	0.98	-154.83	-18.13	0.124	-134.43	0.54	-38.55	5.89
18.00	0.87	-56.87	-1.24	0.87	-170.03	-18.56	0.118	-144.88	0.60	-49.70	5.39

ATF-35143 Typical Scattering Parameters,  $V_{DS} = 2 V$ ,  $I_{DS} = 30 mA$ 

 $V_{DS} = 2 V, I_{DS} = 30 mA$ 

Freq.	<b>F</b> <sub>min</sub>	Γο	pt	R <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.11	0.87	2.7	0.18	21.6
0.9	0.15	0.81	12.1	0.17	20.2
1.0	0.16	0.80	14.5	0.16	19.9
1.5	0.22	0.73	26.3	0.15	18.7
1.8	0.25	0.69	33.4	0.15	18.0
2.0	0.27	0.66	38.1	0.14	17.7
2.5	0.33	0.60	50.6	0.13	17.0
3.0	0.39	0.54	64.2	0.12	16.2
4.0	0.52	0.45	94.0	0.10	14.8
5.0	0.64	0.39	126.5	0.07	13.5
6.0	0.77	0.34	160.6	0.05	12.4
7.0	0.90	0.33	-164.7	0.06	11.4
8.0	1.02	0.33	-130.3	0.10	10.5
9.0	1.15	0.36	-97.5	0.18	9.7
10.0	1.28	0.40	-67.0	0.30	9.1



#### Notes:

 $1. \ \ F_{min} \ values at 2 \ GHz \ and higher are based on measurements while the \ F_{mins} \ below 2 \ GHz \ have been extrapolated. The \ F_{min} \ values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATF NP5 test system. From these measurements a true \ F_{min} \ is calculated. Refer to the noise parameter application section for more information.$ 

Freq.	. S <sub>11</sub>			$\mathbf{S}_{21}$			$\mathbf{S}_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-18.76	16.07	6.36	164.73	-32.77	0.023	76.79	0.65	-13.67	24.42
0.75	0.97	-29.12	15.97	6.29	155.93	-29.37	0.034	70.22	0.63	-19.08	22.70
1.00	0.95	-38.28	15.79	6.16	148.37	-27.13	0.044	64.53	0.62	-25.28	21.46
1.50	0.91	-55.52	15.34	5.85	133.87	-24.01	0.063	54.04	0.59	-37.48	19.68
1.75	0.88	-63.78	15.09	5.68	126.95	-22.97	0.071	49.13	0.57	-43.28	19.00
2.00	0.86	-71.79	14.82	5.51	120.22	-22.05	0.079	44.06	0.56	-49.01	18.43
2.50	0.81	-87.55	14.27	5.17	107.29	-20.82	0.091	34.85	0.52	-59.84	17.55
3.00	0.75	-103.15	13.71	4.85	95.00	-19.83	0.102	25.98	0.49	-69.88	16.77
4.00	0.66	-134.65	12.56	4.25	71.95	-18.71	0.116	9.56	0.42	-87.88	15.63
5.00	0.60	-165.16	11.45	3.74	50.50	-18.13	0.124	-5.10	0.35	-105.14	14.79
6.00	0.58	166.12	10.43	3.32	30.44	-17.79	0.129	-19.00	0.29	-122.61	14.11
7.00	0.56	137.25	9.44	2.97	10.91	-17.65	0.131	-32.32	0.23	-141.22	13.55
8.00	0.57	111.11	8.51	2.66	-7.80	-17.59	0.132	-43.61	0.18	-162.07	12.81
9.00	0.60	87.10	7.51	2.38	-26.05	-17.65	0.131	-55.14	0.13	172.01	10.75
10.00	0.64	66.58	6.64	2.15	-43.52	-17.65	0.131	-65.42	0.10	139.11	9.98
11.00	0.68	47.31	5.76	1.94	-61.59	-17.65	0.131	-76.27	0.11	93.44	9.32
12.00	0.71	28.18	4.81	1.74	-79.58	-17.72	0.130	-87.47	0.16	57.88	8.54
13.00	0.74	9.02	3.71	1.53	-96.96	-17.99	0.126	-98.60	0.23	35.32	7.59
14.00	0.77	-4.82	2.61	1.35	-112.95	-18.34	0.121	-107.41	0.29	13.11	6.76
15.00	0.82	-15.65	1.60	1.20	-128.77	-18.56	0.118	-116.63	0.35	-4.62	6.79
16.00	0.82	-28.00	0.51	1.06	-145.23	-18.71	0.116	-126.02	0.42	-19.61	5.79
17.00	0.84	-40.11	-0.55	0.94	-160.01	-18.71	0.116	-136.14	0.49	-29.62	5.54
18.00	0.86	-55.87	-1.68	0.82	-176.05	-19.25	0.109	-146.13	0.55	-41.92	5.05

ATF-35143 Typical Scattering Parameters,  $V_{DS} = 3 \text{ V}$ ,  $I_{DS} = 10 \text{ mA}$ 

 $V_{DS} = 3 \text{ V}, I_{DS} = 10 \text{ mA}$ 

Freq.	<b>F</b> <sub>min</sub>	Го	pt	R <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.12	0.87	4.7	0.21	20.0
0.9	0.16	0.82	13.2	0.19	19.0
1.0	0.17	0.81	15.3	0.19	18.8
1.5	0.22	0.75	25.9	0.17	17.8
1.8	0.26	0.71	32.3	0.16	17.2
2.0	0.28	0.68	36.5	0.16	16.7
2.5	0.33	0.62	47.7	0.14	15.9
3.0	0.39	0.57	59.6	0.13	15.1
4.0	0.49	0.49	85.4	0.10	13.7
5.0	0.60	0.43	113.6	0.08	12.5
6.0	0.71	0.38	143.7	0.05	11.4
7.0	0.81	0.36	175.6	0.05	10.4
8.0	0.92	0.34	-151.3	0.07	9.6
9.0	1.03	0.34	-117.3	0.12	8.9
10.0	1.13	0.35	-82.7	0.21	8.4



#### Notes:

1.  $F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{mins}$  below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true  $F_{min}$  is calculated. Refer to the noise parameter application section for more information.

Freq.	S	511		$\mathbf{S}_{21}$			$\mathbf{S}_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-19.76	17.20	7.24	164.03	-33.15	0.022	76.95	0.60	-14.39	25.17
0.75	0.96	-30.58	17.08	7.14	154.94	-29.90	0.032	69.88	0.58	-20.00	23.47
1.00	0.94	-40.14	16.86	6.97	147.12	-27.54	0.042	64.59	0.57	-26.48	22.20
1.50	0.90	-58.04	16.35	6.57	132.22	-24.58	0.059	54.00	0.54	-39.05	20.47
1.75	0.87	-66.61	16.06	6.35	125.16	-23.48	0.067	49.23	0.52	-45.00	19.78
2.00	0.84	-74.88	15.75	6.13	118.36	-22.62	0.074	44.39	0.50	-50.83	19.19
2.50	0.78	-91.02	15.13	5.71	105.32	-21.41	0.085	35.29	0.47	-61.71	18.27
3.00	0.73	-106.95	14.50	5.31	93.02	-20.45	0.102	27.00	0.44	-71.87	17.47
4.00	0.63	-138.86	13.24	4.59	70.17	-19.41	0.107	11.47	0.37	-89.81	16.32
5.00	0.58	-169.42	12.05	4.00	49.09	-18.79	0.115	-2.18	0.31	-107.23	15.42
6.00	0.56	162.05	10.97	3.53	29.39	-18.34	0.121	-15.36	0.24	-125.21	14.66
7.00	0.55	133.54	9.93	3.14	10.23	-18.06	0.125	-27.97	0.19	-145.42	14.00
8.00	0.56	107.88	8.96	2.81	-8.11	-17.92	0.127	-38.89	0.14	-168.81	12.23
9.00	0.60	84.56	7.95	2.50	-26.04	-17.86	0.128	-50.41	0.11	158.79	10.87
10.00	0.64	64.57	7.06	2.26	-43.28	-17.72	0.130	-60.57	0.09	118.59	10.16
11.00	0.68	45.84	6.16	2.03	-61.06	-17.59	0.132	-71.45	0.12	75.36	9.55
12.00	0.71	27.11	5.19	1.82	-78.75	-17.59	0.132	-83.32	0.18	46.94	8.80
13.00	0.74	8.18	4.09	1.60	-95.88	-17.79	0.129	-94.36	0.25	27.91	7.86
14.00	0.77	-5.58	2.98	1.41	-111.57	-18.06	0.125	-103.78	0.31	7.94	7.09
15.00	0.82	-16.18	1.96	1.25	-127.09	-18.27	0.122	-113.43	0.37	-8.87	7.04
16.00	0.82	-28.41	0.88	1.11	-143.31	-18.42	0.120	-123.35	0.44	-23.42	6.09
17.00	0.85	-40.49	-0.15	0.98	-157.87	-18.49	0.119	-134.06	0.50	-32.96	5.87
18.00	0.86	-56.20	-1.25	0.87	-173.65	-18.86	0.114	-144.46	0.56	-44.64	5.41

ATF-35143 Typical Scattering Parameters,  $V_{DS} = 3 V$ ,  $I_{DS} = 15 mA$ 

 $V_{DS} = 3 \text{ V}, I_{DS} = 15 \text{ mA}$ 

Freq.	<b>F</b> <sub>min</sub>	Γ	pt	R <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.11	0.86	3.5	0.17	21.2
0.9	0.15	0.81	12.1	0.16	19.9
1.0	0.16	0.80	14.3	0.16	19.6
1.5	0.21	0.73	25.1	0.15	18.2
1.8	0.24	0.69	31.6	0.14	17.6
2.0	0.26	0.66	35.9	0.20	17.2
2.5	0.31	0.60	47.2	0.17	16.3
3.0	0.37	0.55	59.4	0.15	15.6
4.0	0.47	0.46	86.0	0.11	14.2
5.0	0.58	0.40	115.4	0.07	12.9
6.0	0.68	0.36	146.8	0.05	11.8
7.0	0.79	0.33	179.8	0.05	10.8
8.0	0.89	0.32	-146.1	0.07	10.0
9.0	1.00	0.32	-111.5	0.13	9.3
10.0	1.10	0.33	-76.8	0.22	8.8



Notes:

 $1. \ \ F_{min} \ values at 2 \ GHz \ and \ higher \ are \ based \ on \ measurements \ while \ the \ F_{mins} \ below \ 2 \ GHz \ have \ been \ extrapolated. \ The \ F_{min} \ values \ are \ based \ on \ a \ set \ of \ 16 \ noise \ figure \ measurements \ made \ at \ 16 \ different \ impedances \ using \ an \ ATN \ NP5 \ test \ system. \ From \ these \ measurements \ a \ true \ F_{min} \ is \ calculated. \ Refer \ to \ the \ noise \ parameter \ application \ section \ for \ more \ information. \$ 

Freq.	5	S <sub>11</sub>		$\mathbf{S}_{21}$			$\mathbf{S}_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-21.01	18.45	8.36	163.08	-33.98	0.020	76.89	0.53	-15.23	26.21
0.75	0.96	-32.39	18.29	8.21	153.62	-30.46	0.030	69.94	0.51	-21.01	24.36
1.00	0.93	-42.42	18.03	7.97	145.49	-28.40	0.038	64.80	0.50	-27.72	23.22
1.50	0.88	-61.18	17.42	7.43	130.11	-25.35	0.054	54.32	0.47	-40.61	21.39
1.75	0.85	-70.01	17.09	7.15	122.91	-24.44	0.060	49.77	0.45	-46.56	20.72
2.00	0.82	-78.57	16.74	6.87	116.00	-23.61	0.066	45.15	0.43	-52.43	20.17
2.50	0.76	-95.09	16.03	6.33	102.87	-22.38	0.076	36.87	0.40	-63.37	19.21
3.00	0.70	-111.30	15.32	5.83	90.60	-21.41	0.085	29.08	0.37	-73.44	18.36
4.00	0.61	-143.48	13.93	4.97	68.04	-20.26	0.097	14.96	0.31	-91.21	17.10
5.00	0.56	-174.00	12.65	4.29	47.37	-19.58	0.105	2.38	0.25	-108.94	16.11
6.00	0.54	157.98	11.50	3.76	28.09	-19.02	0.112	-10.00	0.19	-128.04	15.26
7.00	0.54	130.06	10.42	3.32	9.32	-18.64	0.117	-22.21	0.14	-151.53	13.78
8.00	0.55	105.20	9.42	2.96	-8.66	-18.34	0.121	-32.79	0.11	179.40	12.10
9.00	0.59	82.53	8.39	2.63	-26.26	-18.06	0.125	-44.11	0.09	138.30	11.00
10.00	0.63	63.18	7.49	2.37	-43.25	-17.79	0.129	-54.57	0.09	95.15	10.36
11.00	0.67	44.96	6.56	2.13	-60.82	-17.52	0.133	-66.16	0.14	62.17	9.76
12.00	0.71	26.64	5.58	1.90	-78.23	-17.46	0.134	-78.18	0.20	39.86	9.05
13.00	0.74	7.94	4.46	1.67	-95.07	-17.65	0.131	-89.74	0.27	23.41	8.14
14.00	0.77	-5.53	3.36	1.47	-110.42	-17.86	0.128	-99.72	0.34	5.08	7.40
15.00	0.82	-16.02	2.33	1.31	-125.79	-17.99	0.126	-109.60	0.39	-11.42	7.41
16.00	0.82	-28.09	1.25	1.16	-141.72	-18.06	0.125	-120.39	0.46	-25.74	6.44
17.00	0.85	-40.02	0.23	1.03	-156.00	-18.06	0.125	-131.03	0.51	-35.29	6.19
18.00	0.87	-55.63	-0.85	0.91	-171.48	-18.49	0.119	-141.69	0.57	-46.81	5.71

ATF-35143 Typical Scattering Parameters,  $V_{\rm DS}$  = 3 V,  $I_{\rm DS}$  = 30 mA

 $V_{DS} = 3 \text{ V}, I_{DS} = 30 \text{ mA}$ 

Freq.	<b>F</b> <sub>min</sub>	Г	pt	<b>R</b> <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.11	0.87	3.5	0.18	21.6
0.9	0.16	0.81	12.5	0.17	20.5
1.0	0.17	0.79	14.7	0.17	20.2
1.5	0.23	0.72	25.9	0.16	18.9
1.8	0.27	0.68	32.6	0.15	18.3
2.0	0.28	0.65	37.1	0.15	17.9
2.5	0.35	0.59	49.3	0.14	17.0
3.0	0.41	0.53	62.5	0.12	16.3
4.0	0.53	0.43	91.6	0.09	14.9
5.0	0.66	0.37	123.4	0.07	13.6
6.0	0.79	0.33	157.1	0.05	12.4
7.0	0.91	0.31	-168.3	0.06	11.4
8.0	1.04	0.31	-133.7	0.10	10.6
9.0	1.17	0.33	-100.0	0.17	9.9
10.0	1.29	0.38	-68.1	0.28	9.3



#### Notes:

1.  $F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{mins}$  below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true  $F_{min}$  is calculated. Refer to the noise parameter application section for more information.

Freq.	5	S <sub>11</sub>		$S_{21}$			$S_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-21.11	18.54	8.45	163.20	-33.98	0.020	77.63	0.56	-14.66	26.26
0.75	0.96	-32.57	18.38	8.30	153.72	-30.75	0.029	70.15	0.54	-20.35	24.55
1.00	0.94	-42.70	18.13	8.07	145.56	-28.64	0.037	64.68	0.53	-26.91	23.38
1.50	0.88	-61.55	17.53	7.53	130.19	-25.68	0.052	53.94	0.50	-39.45	21.61
1.75	0.85	-70.46	17.20	7.24	123.00	-24.58	0.059	49.29	0.48	-45.29	20.90
2.00	0.82	-79.07	16.84	6.95	116.04	-23.88	0.064	44.64	0.46	-50.94	20.36
2.50	0.76	-95.78	16.14	6.41	102.91	-22.62	0.074	36.30	0.43	-61.54	19.38
3.00	0.71	-112.14	15.43	5.91	90.63	-21.72	0.082	28.32	0.40	-71.17	18.58
4.00	0.62	-144.46	14.04	5.03	68.03	-20.72	0.092	13.98	0.34	-87.95	17.38
5.00	0.57	-174.93	12.76	4.34	47.35	-20.00	0.100	1.12	0.28	-104.23	16.38
6.00	0.55	157.13	11.61	3.81	28.07	-19.49	0.106	-11.07	0.22	-120.69	15.55
7.00	0.55	129.56	10.54	3.37	9.35	-19.25	0.109	-23.07	0.17	-139.29	14.19
8.00	0.57	104.96	9.55	3.00	-8.62	-18.94	0.113	-33.33	0.13	-160.54	12.47
9.00	0.60	82.47	8.53	2.67	-26.19	-18.79	0.115	-44.34	0.09	169.67	11.33
10.00	0.64	63.23	7.64	2.41	-43.13	-18.49	0.119	-54.44	0.07	128.74	10.70
11.00	0.68	45.01	6.74	2.17	-60.63	-18.27	0.122	-65.68	0.09	78.47	10.10
12.00	0.72	26.69	5.79	1.95	-78.09	-18.13	0.124	-77.35	0.15	47.96	9.40
13.00	0.74	8.00	4.71	1.72	-95.00	-18.27	0.122	-88.59	0.22	28.53	8.47
14.00	0.77	-5.46	3.64	1.52	-110.50	-18.42	0.120	-98.13	0.28	8.38	7.69
15.00	0.82	-16.18	2.65	1.36	-126.04	-18.49	0.119	-108.03	0.34	-8.46	7.76
16.00	0.82	-28.39	1.62	1.21	-142.14	-18.49	0.119	-118.41	0.40	-22.93	6.75
17.00	0.85	-40.51	0.64	1.08	-156.61	-18.49	0.119	-129.54	0.46	-32.29	6.53
18.00	0.86	-56.36	-0.44	0.95	-172.55	-18.86	0.114	-140.19	0.52	-43.97	6.00

ATF-35143 Typical Scattering Parameters,  $V_{\rm DS}$  = 4 V,  $I_{\rm DS}$  = 30 mA

 $V_{DS} = 4 \text{ V}, I_{DS} = 30 \text{ mA}$ 

Freq.	F <sub>min</sub>	Γα	pt	R <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.10	0.90	3.5	0.22	20.7
0.9	0.14	0.85	12.5	0.21	19.7
1.0	0.16	0.83	14.7	0.20	19.5
1.5	0.21	0.77	25.9	0.18	18.4
1.8	0.25	0.73	32.6	0.17	17.8
2.0	0.28	0.70	37.1	0.17	17.5
2.5	0.33	0.64	49.1	0.15	16.7
3.0	0.38	0.58	62.0	0.14	16.0
4.0	0.49	0.48	90.3	0.10	14.7
5.0	0.62	0.40	121.2	0.07	13.5
6.0	0.74	0.35	154.0	0.05	12.5
7.0	0.87	0.32	-172.2	0.06	11.5
8.0	0.99	0.31	-138.0	0.09	10.7
9.0	1.11	0.34	-104.2	0.15	10.0
10.0	1.24	0.39	-71.6	0.26	9.5



#### Notes:

1.  $F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{mins}$  below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true  $F_{min}$  is calculated. Refer to the noise parameter application section for more information.

Freq.	5	S <sub>11</sub>		$S_{21}$			$S_{12}$		S	22	MSG/MAG
GHz	Mag.	Ang.	dB	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	dB
0.50	0.99	-21.27	18.15	8.09	163.09	-34.89	0.018	77.28	0.54	-13.50	26.52
0.75	0.96	-32.77	17.99	7.94	153.59	-31.70	0.026	70.40	0.53	-18.54	24.83
1.00	0.94	-42.95	17.74	7.71	145.40	-29.37	0.034	65.05	0.51	-24.50	23.55
1.50	0.88	-61.92	17.13	7.19	129.98	-26.56	0.047	55.14	0.48	-35.90	21.84
1.75	0.85	-70.88	16.79	6.91	122.76	-25.51	0.053	50.40	0.47	-41.17	21.15
2.00	0.82	-79.55	16.45	6.64	115.80	-24.73	0.058	46.34	0.45	-46.33	20.59
2.50	0.76	-96.36	15.74	6.12	102.60	-23.48	0.067	38.10	0.42	-55.86	19.61
3.00	0.70	-112.86	15.03	5.64	90.26	-22.62	0.074	30.61	0.39	-64.53	18.82
4.00	0.61	-145.47	13.64	4.81	67.52	-21.51	0.084	17.18	0.34	-79.32	17.58
5.00	0.57	-176.15	12.35	4.15	46.76	-20.82	0.091	5.47	0.29	-93.48	16.59
6.00	0.55	155.85	11.21	3.64	27.45	-20.26	0.097	-5.83	0.24	-107.07	15.74
7.00	0.55	128.25	10.14	3.21	8.68	-19.83	0.102	-17.10	0.19	-121.43	13.17
8.00	0.57	103.61	9.16	2.87	-9.34	-19.41	0.107	-26.34	0.15	-137.04	11.94
9.00	0.60	81.11	8.14	2.55	-27.02	-19.09	0.111	-36.93	0.11	-156.16	10.99
10.00	0.64	62.01	7.25	2.30	-44.01	-18.71	0.116	-46.43	0.07	178.65	10.38
11.00	0.69	43.90	6.37	2.08	-61.57	-18.27	0.122	-57.09	0.06	113.63	9.88
12.00	0.72	25.78	5.43	1.87	-79.17	-17.92	0.127	-68.92	0.10	60.75	9.26
13.00	0.75	7.31	4.37	1.65	-96.36	-17.92	0.127	-80.43	0.18	35.69	8.35
14.00	0.78	-6.12	3.30	1.46	-112.19	-17.92	0.127	-90.26	0.25	13.24	7.57
15.00	0.83	-16.62	2.29	1.30	-127.94	-17.86	0.128	-100.79	0.31	-4.12	7.78
16.00	0.84	-28.78	1.25	1.16	-144.27	-17.79	0.129	-112.14	0.39	-19.12	6.73
17.00	0.87	-40.91	0.21	1.03	-159.19	-17.79	0.129	-123.71	0.46	-28.89	6.65
18.00	0.88	-56.66	-0.92	0.90	-175.28	-17.99	0.126	-134.88	0.52	-40.92	6.06

ATF-35143 Typical Scattering Parameters,  $V_{\rm DS}$  = 4 V,  $I_{\rm DS}$  = 60 mA

 $V_{DS} = 4 \text{ V}, I_{DS} = 60 \text{ mA}$ 

Freq.	<b>F</b> <sub>min</sub>	Γα	pt	R <sub>n/50</sub>	Ga
GHz	dB	Mag.	Ang.	-	dB
0.5	0.22	0.84	4.4	0.29	22.5
0.9	0.30	0.78	15.6	0.29	21.3
1.0	0.32	0.77	18.4	0.28	21.0
1.5	0.42	0.70	32.4	0.26	19.8
1.8	0.48	0.65	40.8	0.25	19.2
2.0	0.52	0.63	46.4	0.24	18.8
2.5	0.63	0.56	61.0	0.21	17.8
3.0	0.73	0.51	76.6	0.19	17.0
4.0	0.94	0.44	109.9	0.13	15.5
5.0	1.15	0.40	144.8	0.09	14.1
6.0	1.35	0.39	-179.8	0.08	12.9
7.0	1.56	0.40	-145.5	0.13	11.9
8.0	1.77	0.43	-113.7	0.26	11.0
9.0	1.98	0.47	-85.6	0.48	10.3
10.0	2.18	0.53	-62.6	0.79	9.8



#### Notes:

 $1. \ \ F_{min} \ values at 2 \ GHz \ and \ higher \ are \ based \ on \ measurements \ while \ the \ F_{mins} \ below \ 2 \ GHz \ have \ been \ extrapolated. \ The \ F_{min} \ values \ are \ based \ on \ a \ set \ of \ 16 \ noise \ figure \ measurements \ made \ at \ 16 \ different \ impedances \ using \ an \ ATN \ NP5 \ test \ system. \ From \ these \ measurements \ a \ true \ F_{min} \ is \ calculated. \ Refer \ to \ the \ noise \ parameter \ application \ section \ for \ more \ information. \$ 

## Noise Parameter Applications Information

F<sub>min</sub> values at 2 GHz and higher are based on measurements while the  $F_{mins}$  below 2 GHz have been extrapolated. The F<sub>min</sub> values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements, a true F<sub>min</sub> is calculated.  $F_{min}$  represents the true minimum noise figure of the device when the device is presented with an impedance matching network that transforms the source impedance, typically 50 $\Omega$ , to an impedance represented by the reflection coefficient  $\Gamma_0$ . The designer must design a matching network that will present  $\Gamma_0$  to the device with minimal associated circuit losses. The noise figure of the completed amplifier is equal to the noise figure of the device plus the losses of the matching network preceding the device. The noise figure of the device is equal to F<sub>min</sub> only when the device is

presented with  $\Gamma_o$ . If the reflection coefficient of the matching network is other than  $\Gamma_o$ , then the noise figure of the device will be greater than  $F_{min}$  based on the following equation.

NF = F<sub>min</sub> + 4 R<sub>n</sub> 
$$\frac{|\Gamma_s - \Gamma_o|^2}{|1 + \Gamma_o|^2(1 - \Gamma_o|^2)}$$

Where  $R_n/Z_o$  is the normalized noise resistance,  $\Gamma_0$  is the optimum reflection coefficient required to produce  $F_{min}$  and  $\Gamma_s$  is the reflection coefficient of the source impedance actually presented to the device. The losses of the matching networks are non-zero and they will also add to the noise figure of the device creating a higher amplifier noise figure. The losses of the matching networks are related to the Q of the components and associated printed circuit board loss.  $\Gamma_0$  is typically fairly low at higher frequencies and increases as frequency is lowered. Larger gate width devices will typically have a lower  $\Gamma_0$  as compared to narrower gate width devices.

Typically for FETs, the higher  $\Gamma_0$ usually infers that an impedance much higher than  $50\Omega$  is required for the device to produce F<sub>min</sub>. At VHF frequencies and even lower L Band frequencies, the required impedance can be in the vicinity of several thousand ohms. Matching to such a high impedance requires very hi-Q components in order to minimize circuit losses. As an example at 900 MHz, when airwwound coils (Q>100) are used for matching networks, the loss can still be up to 0.25 dB which will add directly to the noise figure of the device. Using muiltilayer molded inductors with Qs in the 30 to 50 range results in additional loss over the airwound coil. Losses as high as 0.5 dB or greater add to the typical 0.15 dB F<sub>min</sub> of the device creating an amplifier noise figure of nearly 0.65 dB. A discussion concerning calculated and measured circuit losses and their effect on amplifier noise figure is covered in Agilent Application 1085.

### ATF-35143 SC-70 4 Lead, High Frequency Model

Optimized for 0.1-6.0 GHz



This model can be used as a design tool. It has been tested on MDS for various specifications. However, for more precise and accurate design, please refer to the measured data in this data sheet. For future improvements Agilent reserves the right to change these models without prior notice.

ATF-35143 Die Model

	* ST	ATZ MESFET MODEL MODEL = FET	_ *	
IDS model NFET=yes PFET= IDSMOD=3 VTO=-0.95 BETA= Beta	Gate model DELTA=.2 GSCAP=3 CGS=cgs pF GDCAP=3 GCD=Cgd pF	Parasitics RG=1 RD=Rd RS=Rs LG=Lg nH LD=Ld nH	Breakdown GSFWD=1 GSREV=0 GDFWD=1 GDREV=0 VJR=1	Noise FNC=01e+6 R=.17 P=.65 C=.2
LAMBDA=0.09 ALPHA=4.0 B=0.8 TNOM=27 IDSTC= VBI=.7		LS=Ls nH CDS=Cds pF CRF=.1 RC=Rc	IS=1 nA IR=1 nA IMAX=.1 XTI= N= EG=	

Model scal factors (W=FET width in microns)

EQUATION Cds=0.01\*W/200 EQUATION Beta=0.06\*W/200 EQUATION Rd=200/W

EQUATION Rs=.5\*200/W EQUATION Cgs=0.2\*W/200

EQUATION Cgd=0.04\*W/200 EQUATION Lg=0.03\*200/W

EQUATION Ld=0.03\*200/W EQUATION Ls=0.01\*200/W EQUATION Rc=500\*200/W





Part Number	No. of Devices	Container
ATF-35143-TR1	3000	7" Reel
ATF-35143-TR2	10000	13" Reel
ATF-35143-BLK	100	antistatic bag
ATF-35143-TR1G	3000	7" Reel
ATF-35143-TR2G	10000	13" Reel
ATF-35143-BLKG	100	antistatic bag

### **Part Number Ordering Information**

**Note:** For lead-free option, the part number will have the character "G" at the end.

### Package Dimensions SC-70 4L/SOT-343





	DIMENSIONS (mm)				
SYMBOL	MIN.	MAX.			
E	1.15	1.35			
D	1.85	2.25			
HE	1.80	2.40			
Α	0.80	1.10			
A2	0.80	1.00			
A1	0.00	0.10			
b	0.25	0.40			
b1	0.55	0.70			
С	0.10	0.20			
L	0.10	0.46			



NOTES:

- 1. All dimensions are in mm.
- 2. Dimensions are inclusive of plating.
- 3. Dimensions are exclusive of mold flash & metal burr.
- 4. All specifications comply to EIAJ SC70.
- 5. Die is facing up for mold and facing down for trim/form, ie: reverse trim/form.
- 6. Package surface to be mirror finish.







### **Tape Dimensions and Product Orientation** For Outline 4T

### www.agilent.com/semiconductors

For product information and a complete list of distributors, please go to our web site. For technical assistance call: Americas/Canada: +1 (800) 235-0312 or (916) 788-6763 Europe: +49 (0) 6441 92460 China: 10800 650 0017 Hong Kong: (65) 6756 2394 India, Australia, New Zealand: (65) 6755 1939 Japan: (+81 3) 3335-8152(Domestic/International), or 0120-61-1280(Domestic Only) Korea: (65) 6755 1989 Singapore, Malaysia, Vietnam, Thailand, Philippines, Indonesia: (65) 6755 2044 Taiwan: (65) 6755 1843 Data subject to change. Copyright © 2004-2005 Agilent Technologies, Inc. Obsoletes 5989-1918EN August 25, 2005

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